TOSHIBA TRANSISTOR SILICON PNP TRIPLE DIFFUSED TYPE

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DRIVER STAGE AUDIO AMPLIFIER APPLICATIONS HIGH VOLTAGE SWITCHING APPLICATIONS

• High Breakdown Voltage : $V_{CEO} = -150V$

• Low Output Capacitance : Cob=5.0pF (Max.)

• High Transition Frequency: f_T=120MHz (Typ.)

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	v_{CBO}	-150	V
Collector-Emitter Voltage	v_{CEO}	-150	V
Emitter-Base Voltage	$v_{ m EBO}$	-5	V
Collector Current	$I_{\mathbf{C}}$	-50	mA
Base Current	$I_{\mathbf{B}}$	5	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	800	mW
Junction Temperature	${f T_j}$	150	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~150	°C

Unit in mm

5.1 MAX.

0.75MAX.

1.0MAX.

0.6MAX.

1.27

1.27

1.23

2.54

WW. C. W. W. C. W.

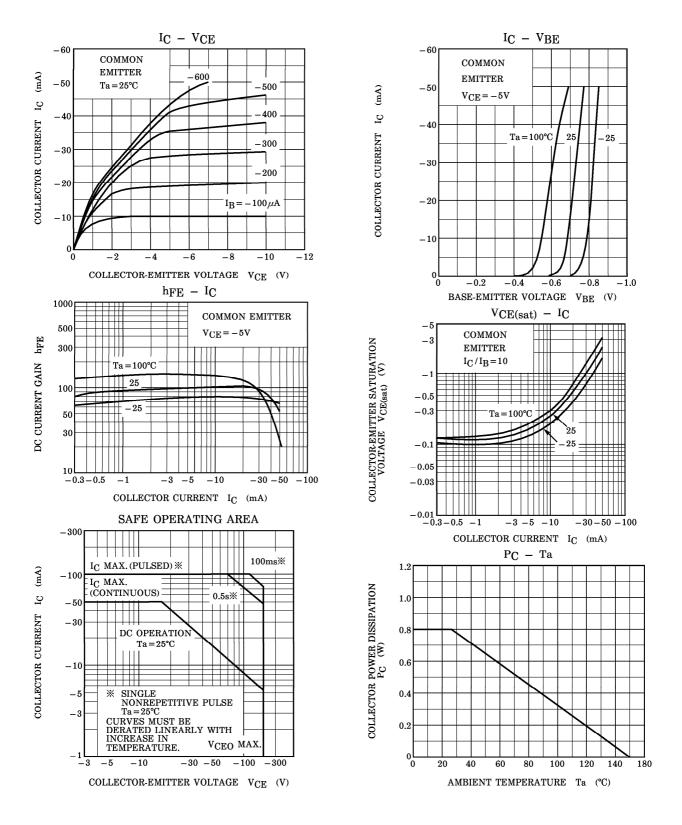
Weight: 0.36g (Typ.)

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

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CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = -150V, I_E = 0$	_	_	-0.1	μ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB} = -5V, I_{C} = 0$	_	_	-0.1	μ A
DC Current Gain	hFE (Note)	$V_{CE} = -5V, I_{C} = -10mA$	70	_	240	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	$I_{C} = -10 \text{mA}, I_{B} = -1 \text{mA}$	_	_	-0.8	V
Base-Emitter Voltage	$v_{ m BE}$	$V_{CE} = -5V, I_{C} = -30mA$	_	_	-0.9	V
Transition Frequency	$ m f_{T}$	$V_{CE} = -30V, I_{C} = -10mA$	_	120	_	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = -10V, I_{E} = 0, f = 1MHz$	_	4.0	5.0	pF

(Note): h_{FE} Classification $O: 70\sim140, Y: 120\sim240$

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